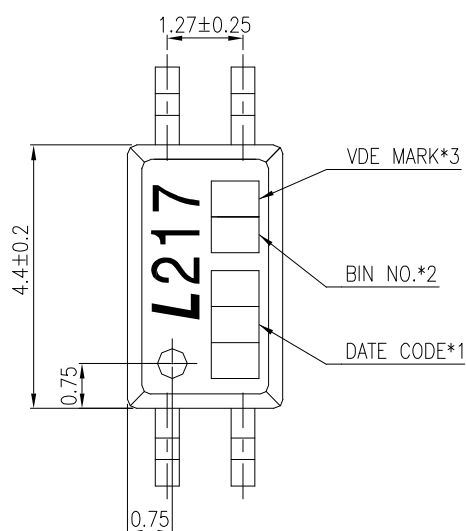
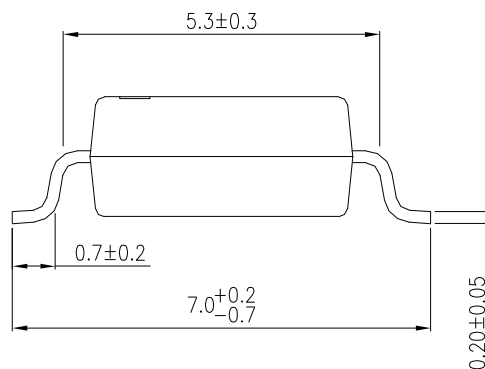
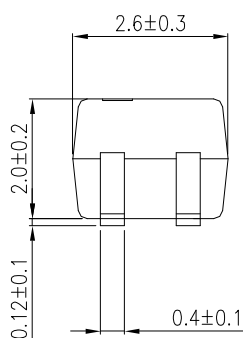
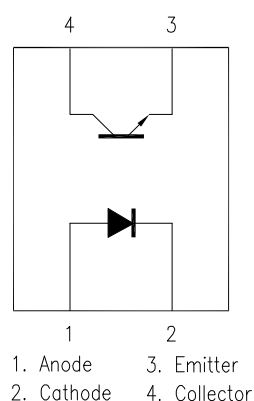


OUTLINE DIMENSIONS

LTV-217 :



Pin No. and Internal connection diagram



*1. 3-digit date code: Y WW

Y : Year code (Ex. A: 2010)

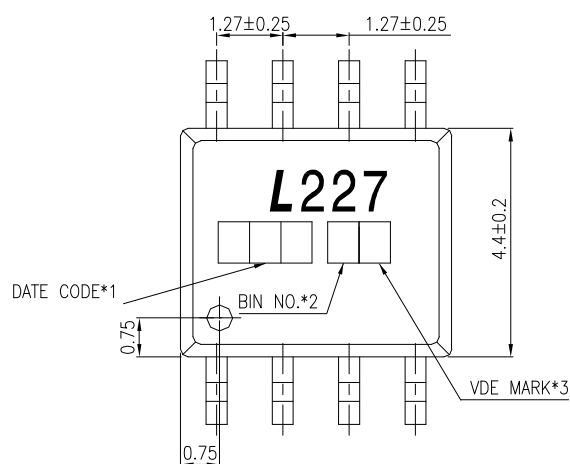
WW : Week code (Ex. 01 : the 1st week in that year)

*2. Rank shall be or shall not be marked.

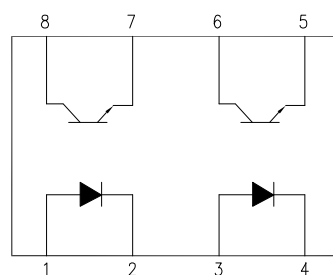
*3. VDE mark only appears on devices ordered "V" option.

OUTLINE DIMENSIONS

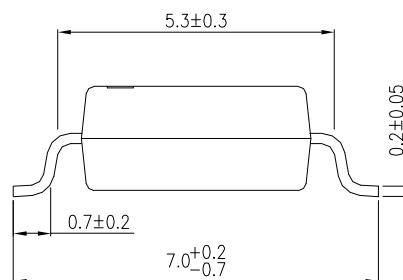
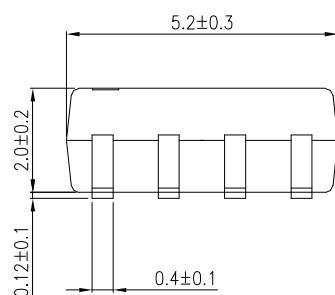
LTV-227:



Pin No. and Internal connection diagram



1,3. Anode
2,4. Cathode
5,7. Emitter
6,8. Collector



*1. 3-digit date code: Y WW

Y : Year code (Ex. A: 2010)

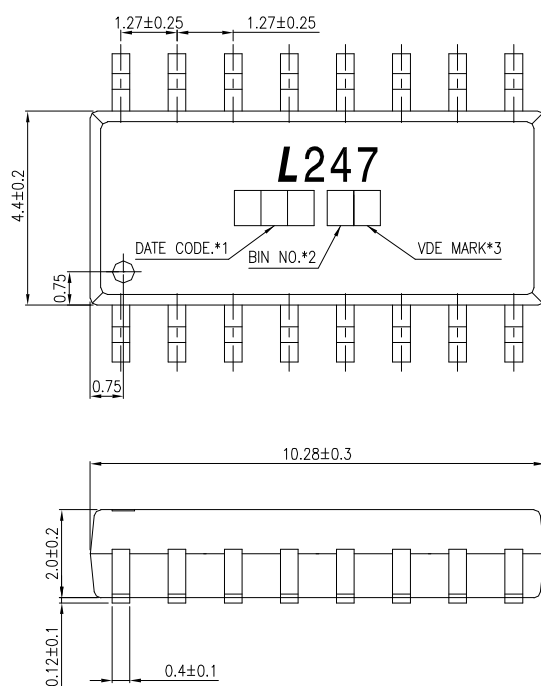
WW : Week code (Ex. 01 : the 1st week in that year)

*2. Rank shall be or shall not be marked.

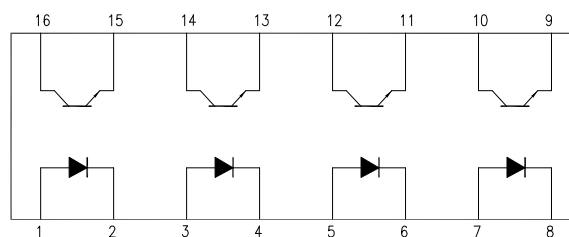
*3. VDE mark only appears on devices ordered "V" option.

OUTLINE DIMENSIONS

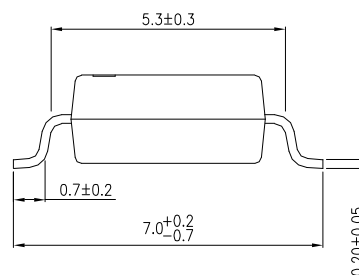
LTV-247 :



PIN NO. AND INTERNAL CONNECTION DIAGRAM



1,3,5,7. Anode
2,4,6,8. Cathode
9,11,13,15. Emitter
10,12,14,16. Collector



*1. 3-digit date code: Y WW

Y : Year code (Ex. A: 2010)

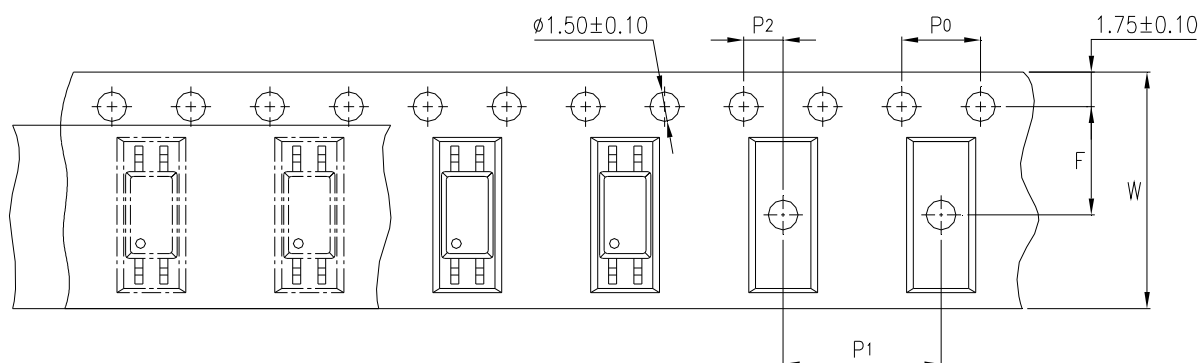
WW : Week code (Ex. 01 : the 1st week in that year)

*2. Rank shall be or shall not be marked.

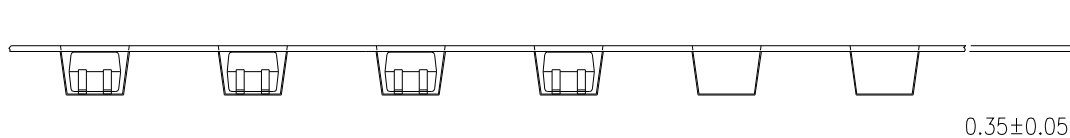
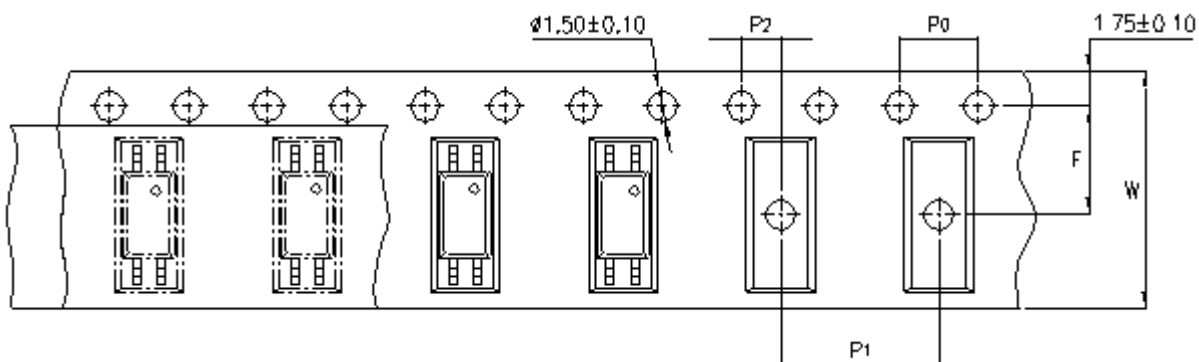
*3. VDE mark only appears on devices ordered "V" option.

TAPING DIMENSIONS

LTV-217 series:



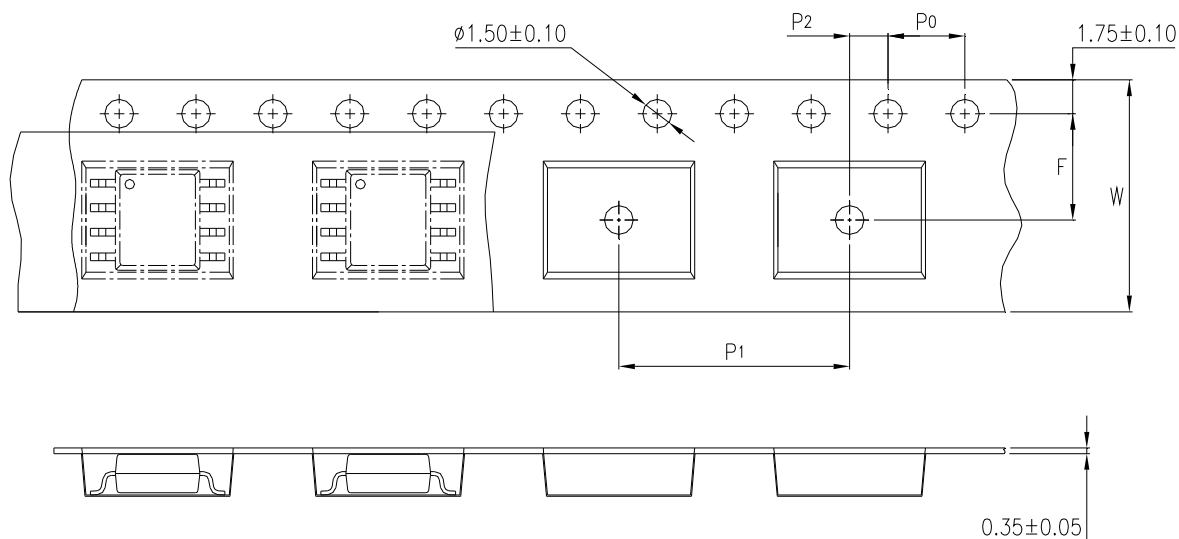
LTV-217-TP1 series



Description	Symbol	Dimension in mm (inches)
Tape wide	W	12 ± 0.3 (.47)
Pitch of sprocket holes	P_0	4 ± 0.1 (.15)
Distance of compartment	F	5.5 ± 0.1 (.217)
Distance of compartment to compartment	P_1	2 ± 0.1 (.079)
	P_2	8 ± 0.1 (.315)

TAPING DIMENSIONS

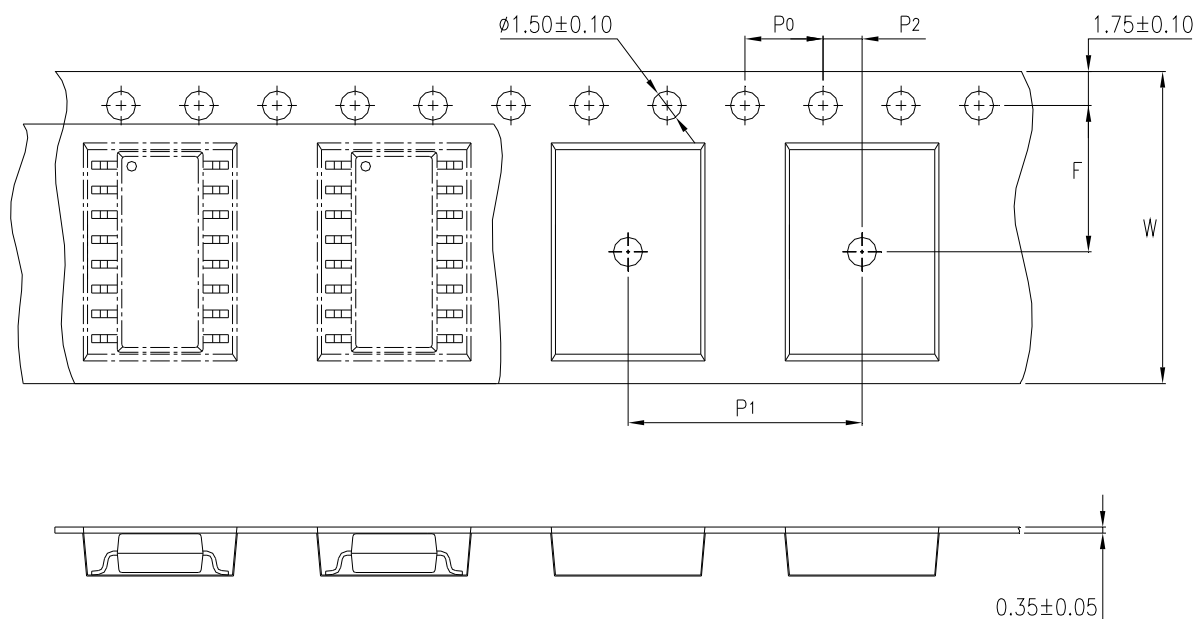
LTV-227 series



Description	Symbol	Dimension in mm (inches)
Tape wide	W	12 ± 0.3 (.47)
Pitch of sprocket holes	P_0	4 ± 0.1 (.15)
Distance of compartment	F P_2	5.5 ± 0.1 (.217) 2 ± 0.1 (.079)
Distance of compartment to compartment	P_1	8 ± 0.1 (.315)

TAPING DIMENSIONS

LTV-247 series:



Description	Symbol	Dimension in mm (inches)
Tape wide	W	16 ± 0.3 (.47)
Pitch of sprocket holes	P₀	4 ± 0.1 (.15)
Distance of compartment	F P₂	7.5 ± 0.1 (.217) 2 ± 0.1 (.079)
Distance of compartment to compartment	P₁	12 ± 0.1 (.63)

Quantities per Reel :

Package Type	LTV-217	LTV-227	LTV-247
Quantities (pcs)	3000	2000	2000

ABSOLUTE MAXIMUM RATING

(Ta = 25°C)

PARAMETER		SYMBOL	RATING			UNIT
			217	227	247	
INPUT	Forward Current	I _F	50			mA
	Reverse Voltage	V _R	6			V
	Power Dissipation	P	70			mW
OUTPUT	Collector - Emitter Voltage	V _{CEO}	80			V
	Emitter - Collector Voltage	V _{ECO}	7			V
	Collector Current	I _C	50			mA
	Collector Power Dissipation	P _C	150		100	mW
Total Power Dissipation		P _{tot}	200		170	mW
*1 Isolation Voltage		V _{iso}	3,750			V _{rms}
Operating Temperature		T _{opr}	-55 ~ +110			°C
Storage Temperature		T _{stg}	-55 ~ +150			°C
*2 Soldering Temperature		T _{sol}	260 (10s)			°C

*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds

ELECTRICAL - OPTICAL CHARACTERISTICS

(Ta = 25°C)

PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
INPUT	Forward Voltage	V _F	—	1.2	1.4	V	I _F =20mA
	Reverse Current	I _R	—	—	10	μA	V _R =4V
	Terminal Capacitance	C _t	—	30	250	pF	V=0, f=1KHz
OUTPUT	Collector Dark Current	I _{CEO}	—	—	100	nA	V _{CE} =48V, I _F =0
	Collector-Emitter Breakdown Voltage	BV _{CEO}	80	—	—	V	I _C =0.1mA I _F =0
	Emitter-Collector Breakdown Voltage	BV _{ECO}	7	—	—	V	I _E =10μA I _F =0
TRANSFER CHARACTERISTICS	Collector Current	I _C	2.5	—	30	mA	I _F =5mA V _{CE} =5V
	*1 Current Transfer Ratio	CTR	50	—	600	%	
	Saturated Current	I _C (sat)	—	4.8	—	mA	I _F =8mA V _{CE} =2.4V
	Saturated CTR	CTR (sat)	—	60	—	%	
	Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	0.4	V	I _F =8mA I _C =2.4mA
	Isolation Resistance	R _{iso}	5×10 ¹⁰	1×10 ¹¹	—	Ω	DC500V 40 ~ 60% R.H.
	Floating Capacitance	C _f	—	0.6	1	pF	V=0, f=1MHz
	Response Time (Rise)	t _r	—	2	—	μs	V _{CE} =10V, I _C =2mA R _L =100Ω
	Response Time (Fall)	t _f	—	3	—	μs	
	Turn-On Time	t _{on}	—	3	—	us	
	Turn-Off Time	t _{off}	—	3	—	us	
	Turn-On Time	t _{ON}	—	2	—	us	V _{CE} =5V, I _C =16mA R _L =1.9KΩ
	Storage Time	t _s	—	25	—	us	
	Turn-Off Time	t _{OFF}	—	40	—	us	

$$*1 \text{ CTR} = \frac{I_C}{I_F} \times 100\%$$

RANK TABLE OF CURRENT TRANSFER RATIO CTR

MODEL NO.	RANK MARK	CTR (%)
LTV-217	A	80 ~ 160
	A1	100 ~ 160
	B	130 ~ 260
	C	200 ~ 400
	D	300 ~ 600
	A or B or C or D or No mark	50 ~ 600
LTV-227	B	130 ~ 260
	C	200 ~ 400
	B or C or No mark	50 ~ 600
LTV-247	No mark	100 ~ 600

CONDITIONS	IF = 5 mA VCE = 5 V Ta = 25 °C
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CHARACTERISTICS CURVES

Figure 1. Collector Power Dissipation vs. Ambient Temperature

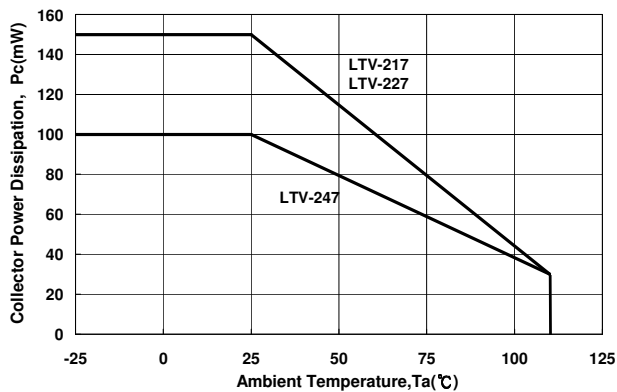


Figure 2. Forward Current vs. Ambient Temperature

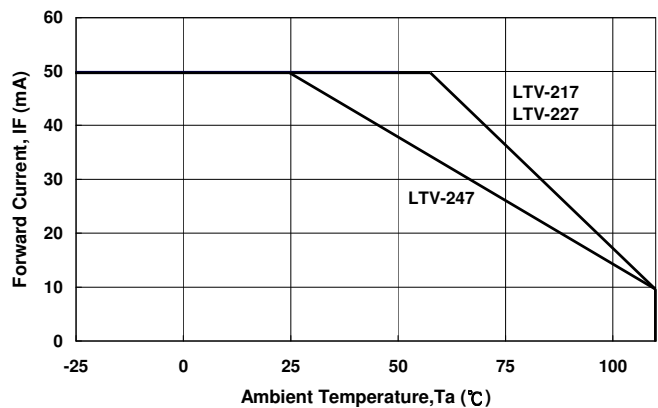


Figure 3. Forward Current vs. Forward Voltage

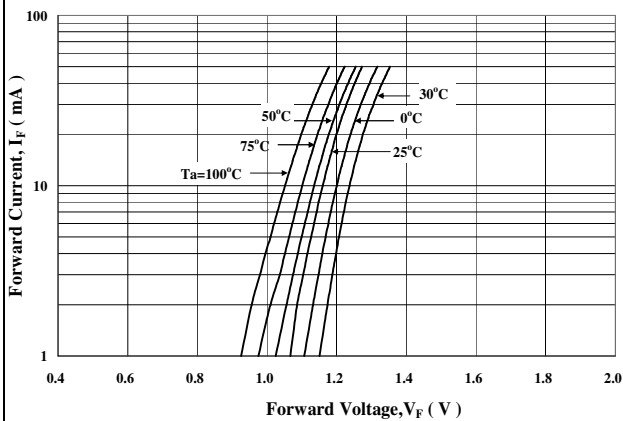


Figure 4. Forward Voltage Temperature Coefficient vs. Forward Current

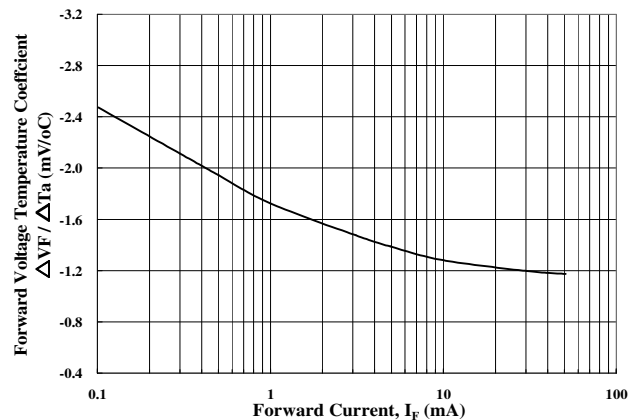


Figure 5. Pulse Forward Current vs. Duty Cycle Ratio

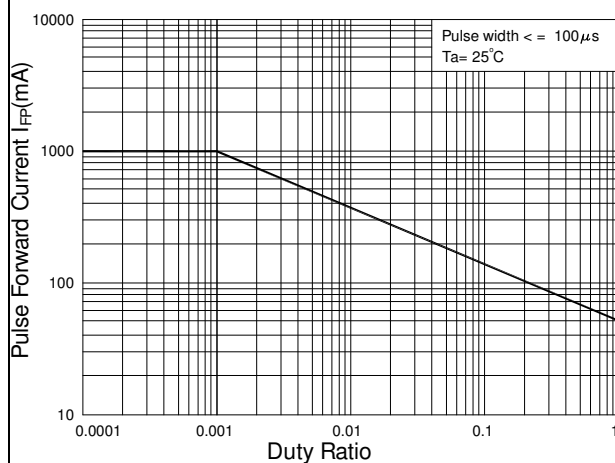
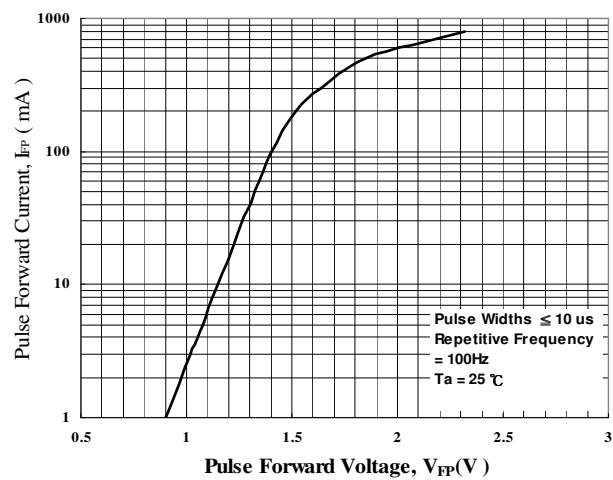


Figure 6. Pulse Forward Current vs. Pulse Forward Voltage



CHARACTERISTICS CURVES

Figure 7. Collector-Emitter Saturation Voltage vs. Forward Current

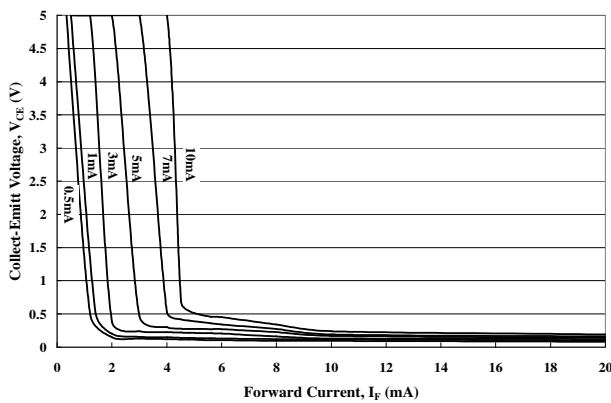


Figure 8. Collector Current vs. Collector-Emitter Voltage

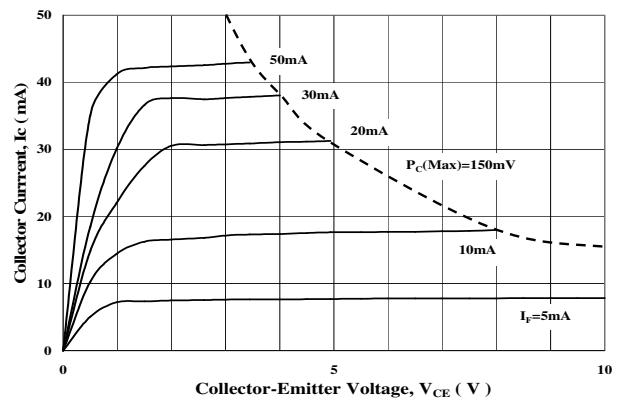


Figure 9. Collector Current vs. Small Collector-Emitter Voltage

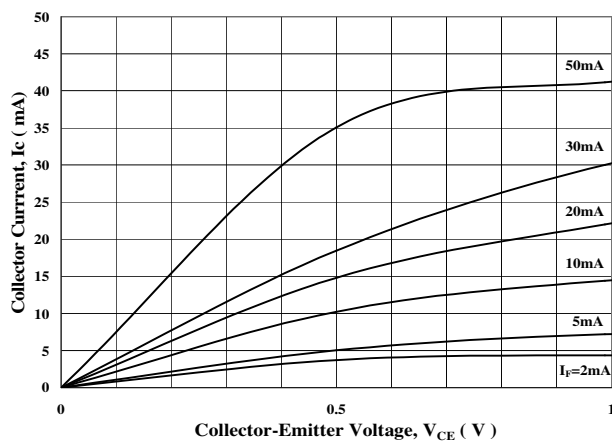


Figure 10. Collector Current vs. Forward Current

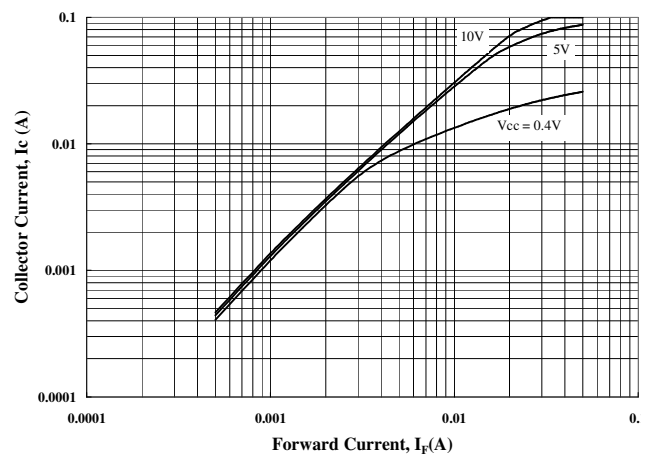


Figure 11. Collector Dark Current vs. Ambient Temperature

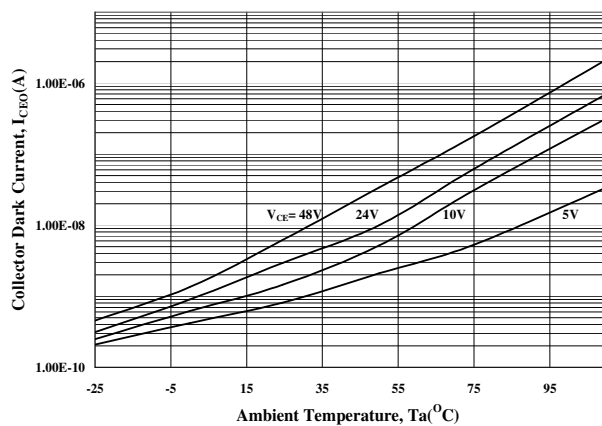
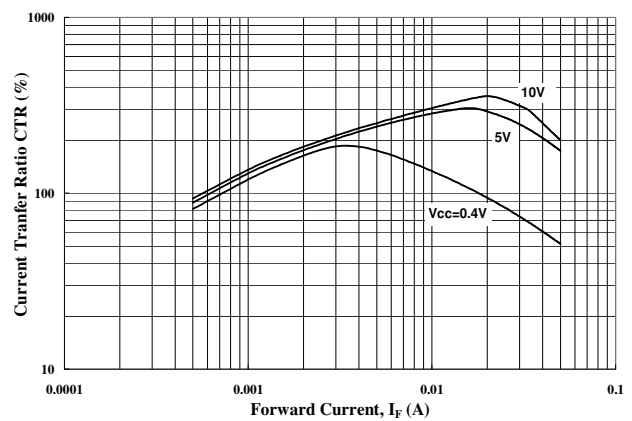


Figure 12. Current Transfer Ratio vs. Forward Current



CHARACTERISTICS CURVES

Figure 13. Collector-Emitter Saturation Voltage vs. Ambient Temperature

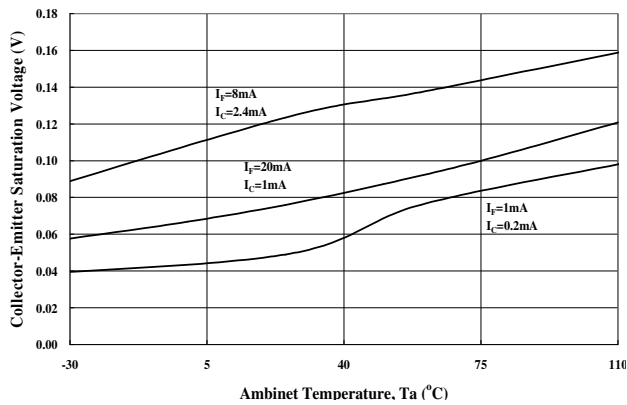


Figure 14. Collector Current vs. Ambient Temperature

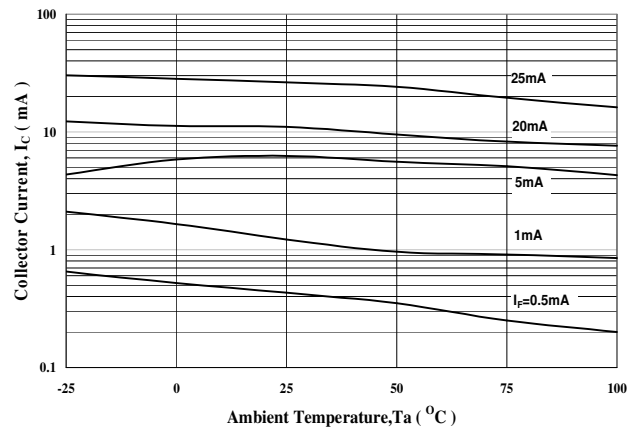


Figure 15. Switching Time vs. Load Resistance

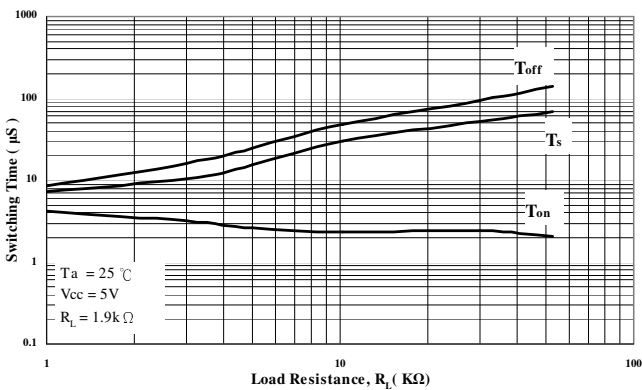


Figure 16. Switching Time vs. Ambient Temperature

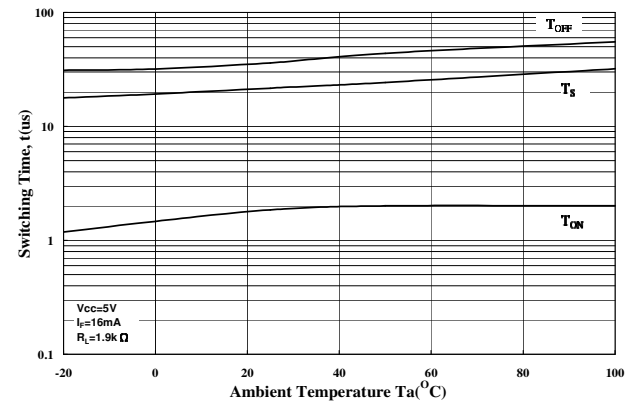
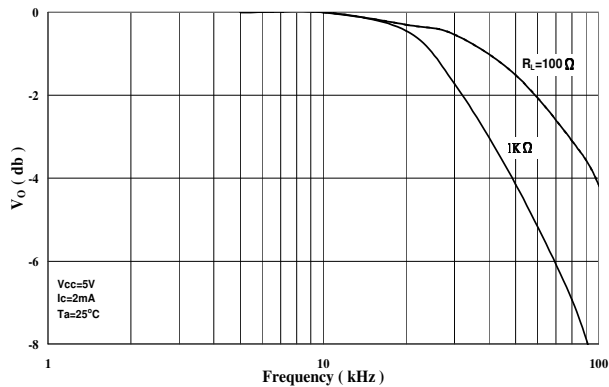
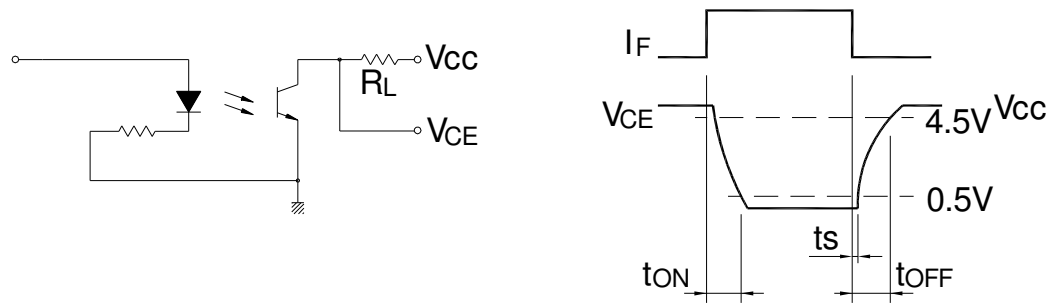


Figure 17. Frequency Response



SWITCHING TIME TEST CIRCUIT



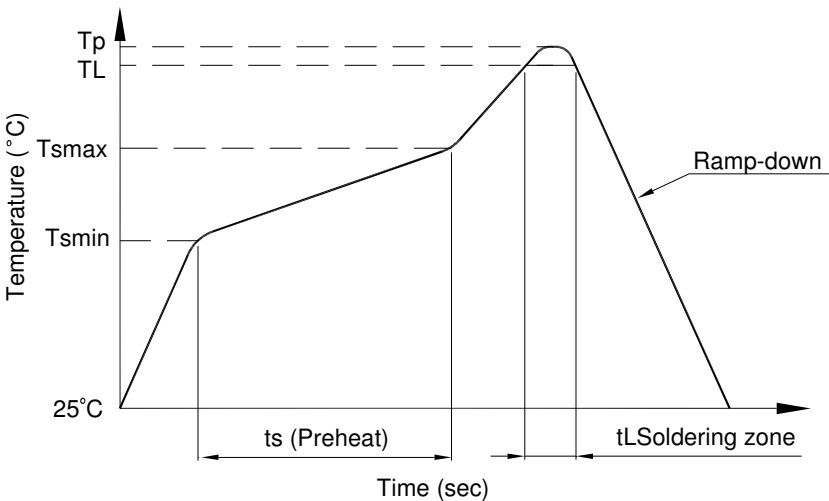
TEMPERATURE PROFILE OF SOLDERING REFLOW

(1) One time soldering reflow is recommended within the condition of temperature and time profile shown below.

- 1. Wave solder
 - 260°C / 10 sec.

- 2. IR Reflow

Profile item	Conditions
Preheat - Temperature Min (T_{Smin}) - Temperature Max (T_{Smax}) - Time (min to max) (t_s)	150°C 180°C $90\pm30^{\circ}\text{C}$
Soldering zone - Temperature (T_L) - Time (t_L)	250°C 10~15 sec
Peak Temperature (T_P)	260°C
Ramp-down rate	$3\sim6^{\circ}\text{C}$ / sec



TEMPERATURE PROFILE OF SOLDERING REFLOW

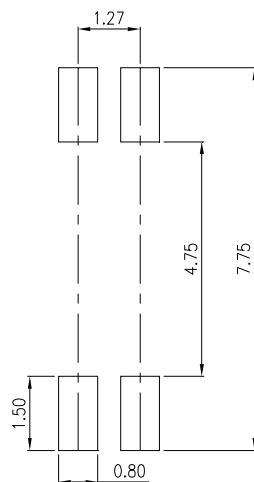
(2) When using another soldering method such as infrared ray lamp, the temperature may rise partially in the mold of the device.

Keep the temperature on the package of the device within the condition of above (1)

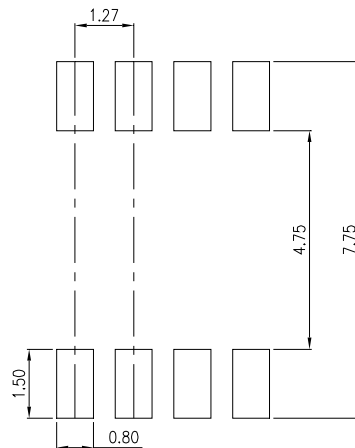
RECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)

Unit:mm

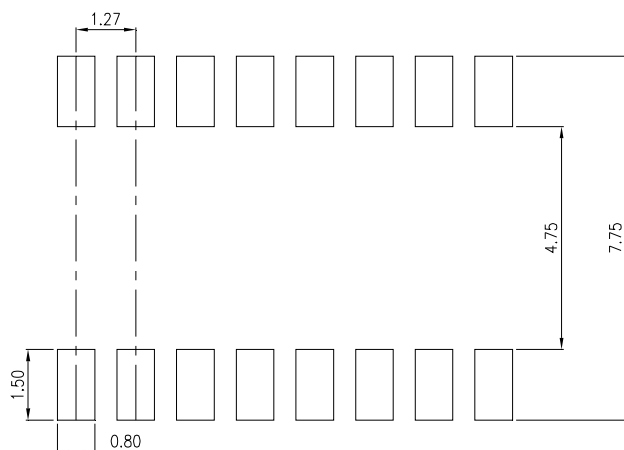
LTV-217 series:



LTV-227 series:



LTV-247 series:



Notes:

- Lite-On is continually improving the quality, reliability, function or design and Lite-On reserves the right to make changes without further notices.
- The products shown in this publication are designed for the general use in electronic applications such as office automation equipment, communications devices, audio/visual equipment, electrical application and instrumentation.
- For equipment/devices where high reliability or safety is required, such as space applications, nuclear power control equipment, medical equipment, etc, please contact our sales representatives.
- When requiring a device for any "specific" application, please contact our sales in advice.
- If there are any questions about the contents of this publication, please contact us at your convenience.
- The contents described herein are subject to change without prior notice.
- Do not immerse unit's body in solder paste.

